

DFM400XXM65-F000

Fast Recovery Dual Diode Module

DS5952-1 November 2009 (LN26928)

FEATURES

- Low Reverse Recovery Charge
- High Switching Speed
- Low Forward Volt Drop
- Isolated AlSiC Base with AIN Substrates
- Dual Diodes can be paralleled for 800A Rating
- Lead Free Construction
- 10.2kV Isolation Package

APPLICATIONS

- Brake Chopper Diodes
- Boost and Buck Circuits
- Free-wheel Circuits
- Motor Drives
- Resonant Converters
- Induction Heating
- Multi-level Switch Inverters

The DFM400XXM65-F000 is a dual 6500V, fast recovery diode (FRD) module. Designed for low power loss, the module is suitable for a variety of high voltage applications in motor drives and power conversion.

Fast switching times and low reverse recovery losses allow high frequency operation, making the device suitable for the latest drive designs employing PWM and high frequency switching.

The module incorporates an electrically isolated base plate and low inductance construction enabling circuit designers to optimise circuit layouts and utilise grounded heat sinks for safety.

ORDERING INFORMATION

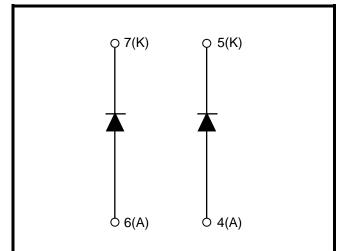
Order As:

DFM400XXM65-F000

Note: When ordering, please use the complete part number

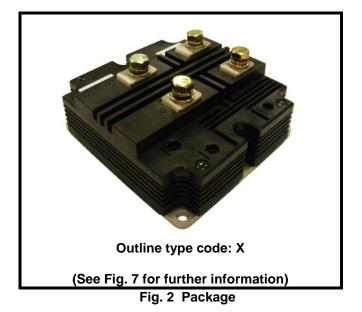
KEY PARAMETERS

V _{RRM}		6500V
V _F	(typ)	3.6V
I _F	(max)	400A
I _{FM}	(max)	800A



External connection required for a single 800A diode

Fig. 1 Circuit configuration



ABSOLUTE MAXIMUM RATINGS

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

T_{case} = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
		T _j = 125°C	6500	V
V _{RRM}	Repetitive peak reverse voltage	$T_j = 25^{\circ}C$	6300	V
		$T_j = -40^{\circ}C$	5800	V
١ _F	Forward current (per arm)	DC, $T_{case} = 75^{\circ}C$, $T_j = 125^{\circ}C$	400	А
I _{FM}	Max. forward current	$T_{case} = 115^{\circ}C, t_{p} = 1ms$	800	А
l ² t	I ² t value fuse current rating	$V_{R} = 0, t_{p} = 10ms, T_{j} = 125^{\circ}C$	97	kA ² s
P _{max}	Max. power dissipation	$T_{case} = 25^{\circ}C, T_j = 125^{\circ}C$	3300	W
V _{isol}	Isolation voltage – per module	Commoned terminals to base plate. AC RMS, 1 min, 50Hz	10200	V
Q _{PD}	Partial discharge – per module	IEC1287, $V_1 = 6900V$, $V_2 = 5100V$, 50Hz RMS	10	рС

THERMAL AND MECHANICAL RATINGS

Internal insulation material:	AIN
Baseplate material:	AISiC
Creepage distance:	56mm
Clearance:	26mm
CTI (Comparative Tracking Index):	> 600

Symbol	Parameter	Test Conditions	Min	Тур.	Мах	Units
R _{th(j-c)}	Thermal resistance (per arm)	Continuous dissipation – junction to case	-	-	30	°C/kW
R _{th(c-h)}	Thermal resistance – case to heatsink (per module)	Mounting torque 5Nm (with mounting grease)	-	-	8	°C/kW
Tj	Junction temperature		-40	-	125	°C
T _{stg}	Storage temperature range		-40	-	125	°C
	Sorow Torque	Mounting – M6	-	-	5	Nm
Sciew rolque	Screw Torque	Electrical connections – M8	-	-	10	Nm

STATIC ELECTRICAL CHARACTERISTICS – PER ARM

T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
I _{RM}	Peak reverse current	V _R = 6500V, T _j = 125°C			40	mA
V _F Forward v		I _F = 400A		3.6		V
	Forward voltage	I _F = 400A, T _j = 125°C		4.1		V
L _M	Inductance	-		40		nH

STATIC ELECTRICAL CHARACTERISTICS

T_{case} = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
L _M	Module inductance (externally connected in parallel)	-		20		nH
R _{INT}	Internal resistance (per arm)	-		370		μΩ

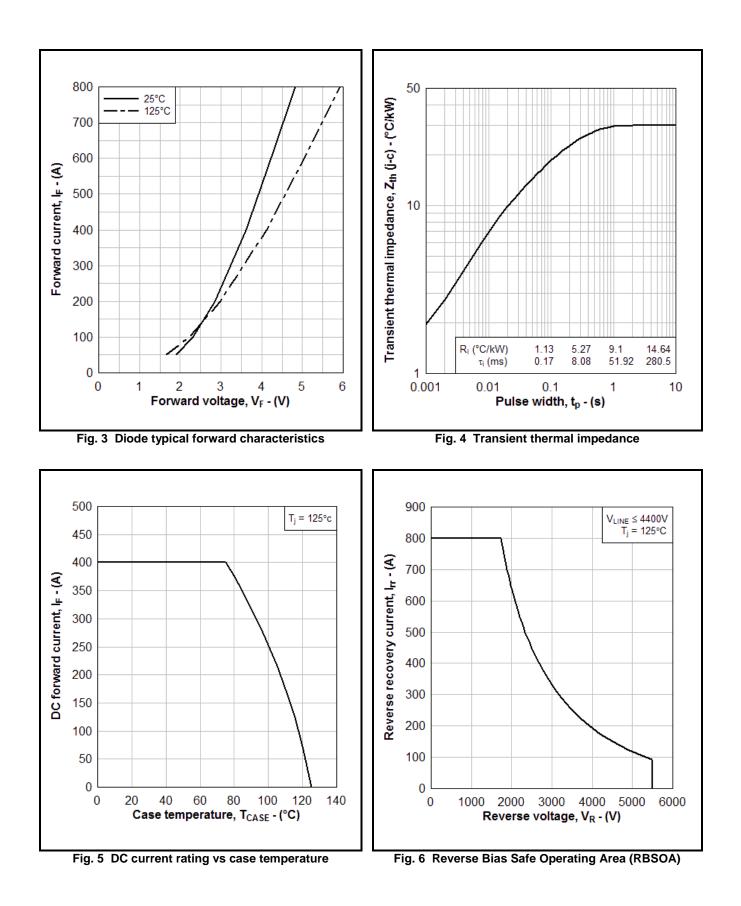
DYNAMIC ELECTRICAL CHARACTERISTICS – PER ARM

T_{case} = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
Q _{rr}	Reverse recovery charge	I _F = 400A		700		μC
I _{rr}	Peak reverse recovery current	V _R = 3600V		300		А
E _{rec}	Reverse recovery energy	dl _F /dt = 1300A/µs		1300		mJ

T_{case} = 125°C unless stated otherwise

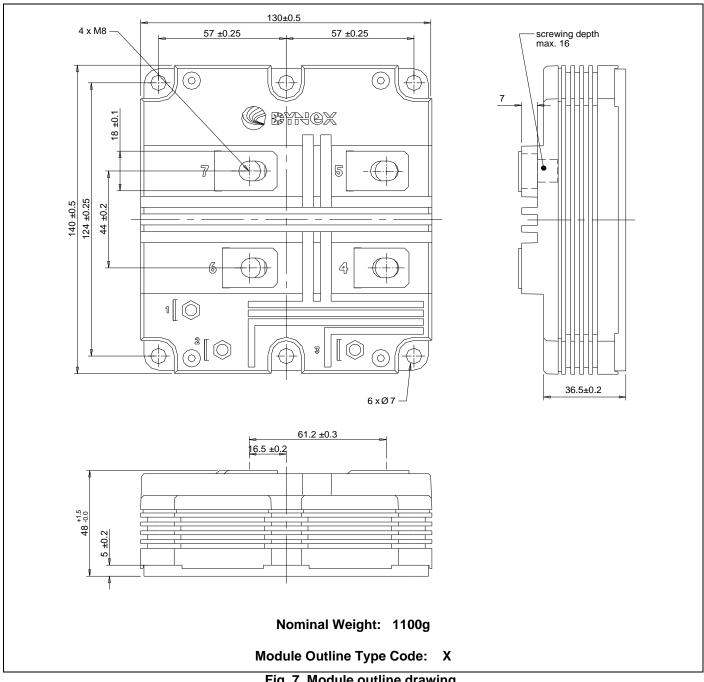
Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
Q _{rr}	Reverse recovery charge	I _F = 400A		1000		μC
I _{rr}	Peak reverse recovery current	V _R = 3600V		370		А
E _{rec}	Reverse recovery energy	dI _F /dt = 1600A/µs		2000		mJ

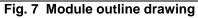




PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





HEADQUARTERS OPERATIONS

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No Annotation:	The product parameters are fixed and the product is available to datasheet specification.

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